NSN 5961-01-352-1798

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Internal Configuration:

Field effect

Semiconductor Material:

Gallium arsenide

Voltage Rating In Volts Per Characteristic:

-6.0 gate to source voltage

Current Rating Per Characteristic:

100.00 milliamperes drain current

Power Rating Per Characteristic:

400.0 milliwatts total power dissipation

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0